

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 150 A



DO-205AA (DO-8)

150 A

PRODUCT SUMMARY

 $I_{F(AV)}$

FEATURES

- · Alloy diode
- · High current carrying capability
- High surge current capabilities
- Stud cathode and stud anode version
- · RoHS compliant
- · Designed and qualified for industrial level

TYPICAL APPLICATIONS

- · Battery chargers
- Welders
- · Machine tool controls
- · High power drives
- Medium traction applications
- · Freewheeling diodes

- 40 to 200

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		150	A	
	T _C	150	°C	
I _{F(RMS)}		235	A	
1	50 Hz	3570	A	
IFSM	60 Hz	3740		
l ² t	50 Hz	64	kA ² s	
	60 Hz	58	KA-5	
V _{RRM}	Range	100 to 600	V	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 175 °C mA	
45L(R) 150K(R) 150KS(R)	10	100	200		
	20	200	300		
	30	300	400	35	
	40	400	500		
	60	600	720		

Document Number: 93489 Revision: 21-May-08

 T_J

°С

45L(R), 150K(R), 150KS(R) Series

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 150 A



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		150	A	
at case temperature	, ,				150	°C
Maximum RMS forward current	I _{F(RMS)}	DC at 142 °C case temperature		235		
		t = 10 ms	No voltage		3570	A kA ² s
Maximum peak, one cycle forward,	I _{FSM}	t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	3740	
non-repetitive surge current		t = 10 ms	100 % V _{RRM} reapplied		3000	
		t = 8.3 ms			3140	
Maximum I ² t for fusing	l ² t t	t = 10 ms	No voltage reapplied		64	
		t = 8.3 ms			58	
		t = 10 ms	100 % V _{RRM}		45	
		t = 8.3 ms	reapplied		41	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied		640	kA²√s	
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.67	V	
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.83	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		1.42	 0	
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.91	mΩ	
Maximum forward voltage drop	V_{FM}	I_{pk} = 471 A, T_J = 25 °C, t_p = 10 ms sinusoidal wave		1.33	V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 200	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.25	14004	
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, flat and greased	0.10	K/W	
	minimum		Not lubricated threads	14.1 (125)	N · m (lbf · in)	
Mounting torque	maximum		Not lublicated tilleads	17.0 (150)		
45L	minimum		Lubricated threads	12.2 (108)		
	maximum		Lublicated tilleads	15.0 (132)		
	minimum		Not lubricated threads	11.3 (100)	N ⋅ m (lbf ⋅ in)	
Mounting torque	maximum		Not lublicated tilleads	14.1 (125)		
150K 150KS	minimum		Lubricated threads	9.5 (85)		
	maximum		Lubricated tiffeads	12.5 (110)		
Approximate weight				100	g	
				3.5	OZ.	
	45L		DO-205AC (D		(DO-30)	
Case style	150K-A	See dimensions - link at the end of datasheet DO-205AA (I		(DO-8)		
	150KS			B-42		



Standard Recovery Diodes (Stud Version), 150 A

Vishay Semiconductors

△R _{thJC} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.031	0.023				
120°	0.038	0.040				
90°	0.048	0.053	$T_J = T_J \text{ maximum}$	K/W		
60°	0.071	0.075				
30°	0.120	0.121				

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

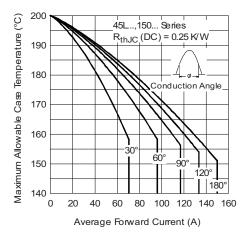


Fig. 1 - Current Ratings Characteristics

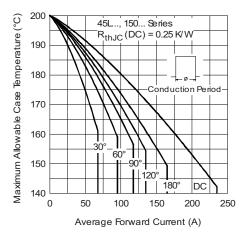


Fig. 2 - Current Ratings Characteristics

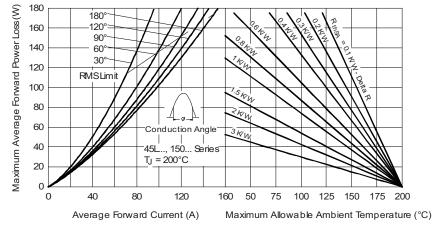


Fig. 3 - Forward Power Loss Characteristics

45L(R), 150K(R), 150KS(R) Series

Vishay Semiconductors

Standard Recovery Diodes (Stud Version), 150 A



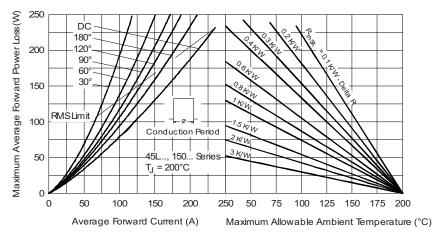


Fig. 4 - Forward Power Loss Characteristics

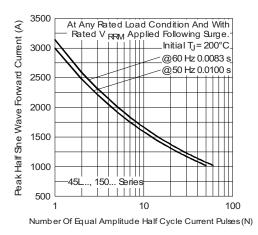


Fig. 5 - Maximum Non-Repetitive Surge Current

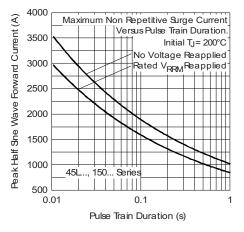


Fig. 6 - Maximum Non-Repetitive Surge Current

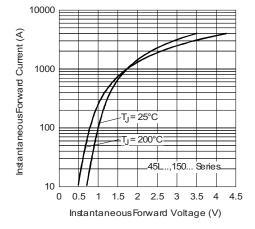


Fig. 7 - Forward Voltage Drop Characteristics



Standard Recovery Diodes (Stud Version), 150 A

Vishay Semiconductors

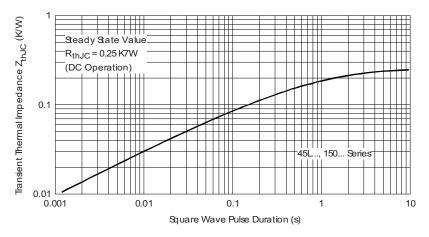
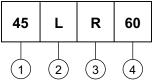


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLES

Device code



1 - 45 = Standard version

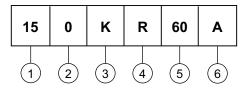
2 - L = Essential part number

R = Stud reverse polarity (anode to stud)

None = Stud normal polarity (cathode to stud)

- Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

Device code



1 - 15 = Essential part number

2 - 0 = Standard device

Case style:K = DO-205AA (DO-8)

KS = B-42

- R = Stud reverse polarity (anode to stud)
None = Stud normal polarity (cathode to stud)

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

6 - A = Essential part number for 150K (omitted for 150KS)

Note: For metric device M12 x 1.75 contact factory

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95314			

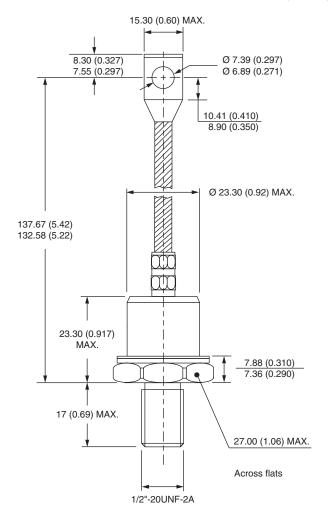
Document Number: 93489 Revision: 21-May-08



Vishay Semiconductors

DO-205AC (DO-30), DO-205AA (DO-8) and B-42 for 45L(R), 150K(R) and 150KS(R) Series

DIMENSIONS FOR 45L(R) SERIES - DO-205AC (DO-30) in millimeters (inches)



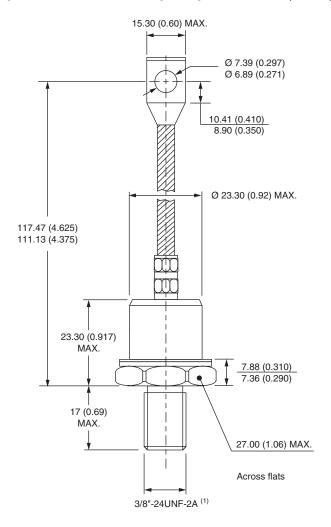
Outline Dimensions

Vishay Semiconductors

DO-205AC (DO-30), DO-205AA (DO-8) and B-42 for 45L(R), 150K(R) and 150KS(R) Series



DIMENSIONS FOR 150K(R) SERIES - DO-205AA (DO-8) in millimeters (inches)



Note

(1) For metric device M12 x 1.75 contact factory

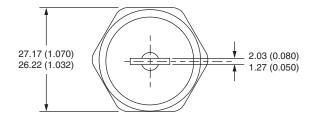
Document Number: 95314 Revision: 22-Jul-08

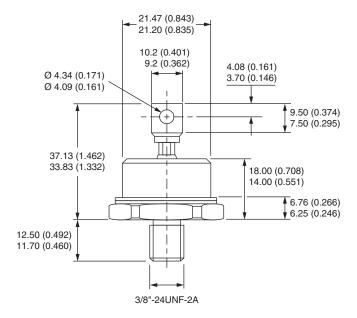


DO-205AC (DO-30), DO-205AA (DO-8) and B-42 for 45L(R), 150K(R) and 150KS(R) Series

Vishay Semiconductors

DIMENSIONS FOR 150KS(R) SERIES - B-42 in millimeters (inches)







Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.